

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	31917	semiconductor and photodiode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/25 11:50
L2	6114	1 and (trench or recess or groove)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/25 11:51
L3	2582	2 and isolat\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/25 11:51
L4	1825	3 and ((aluminum oxide) or (aluminum nitride) or (aluminum silicate))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/25 11:52
L5	1339	4 and (charge or carrier)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/25 11:53
L6	649	5 and pixel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/25 11:53